

PT480/PT480F

Narrow Acceptance Phototransistor

■ Features

1. Epoxy resin package
2. Narrow acceptance ($\Delta\theta$: TYP. $\pm 13^\circ$)
3. Visible light cut-off type : **PT480F**

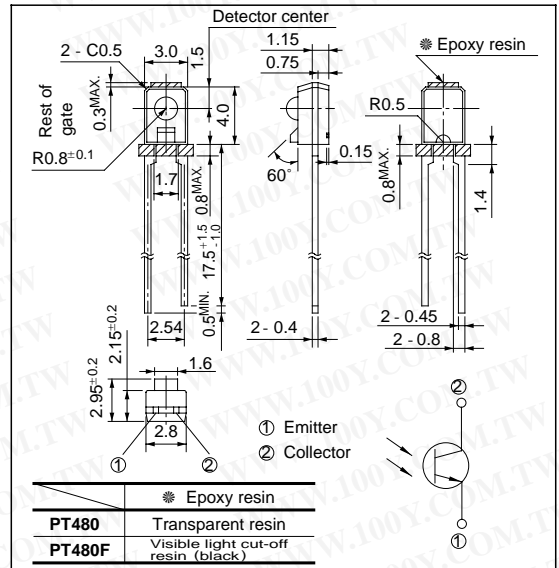
■ Applications

1. VCRs, cassette tape recorders
2. Floppy disk drives
3. Optoelectronic switches
4. Automatic stroboscopes

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■ Outline Dimensions

(Unit : mm)



■ Absolute Maximum Ratings

(Ta = 25°C)

Parameter	Symbol	Rating	Unit
Collector-emitter voltage	V_{CEO}	35	V
Emitter-collector voltage	V_{ECO}	6	V
Collector current	I_C	20	mA
Collector power dissipation	P_C	75	mW
Operating temperature	T_{opr}	- 25 to + 85	°C
Storage temperature	T_{stg}	- 40 to + 85	°C
*1 Soldering temperature	T_{sol}	260	°C

*1 For 5 seconds at the position of 1.4mm from the bottom face of resin package

■ Electro-optical Characteristics

(Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*2 Collector current	I_C	$V_{CE} = 5V$	0.4	1.7	6.0	mA
		$E_e = 1mW/cm^2$	0.25	0.8	3.0	mA
Collector dark current	I_{CEO}	$V_{CE} = 20V, E_e = 0$	-	10^{-9}	10^{-7}	A
*2 Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 0.5mA, E_e = 10mW/cm^2$	-	0.1	0.4	V
Peak sensitivity wavelength	λ_P	-	-	800	-	nm
			-	860	-	nm
Response time	Rise time	$V_{CE} = 2V, I_C = 2mA$	-	3	-	μs
	Fall time	$R_L = 100\Omega$	-	3.5	-	μs

*2 E_e : Irradiance by CIE standard light source A (tungsten lamp)

Fig. 1 Collector Power Dissipation vs. Ambient Temperature

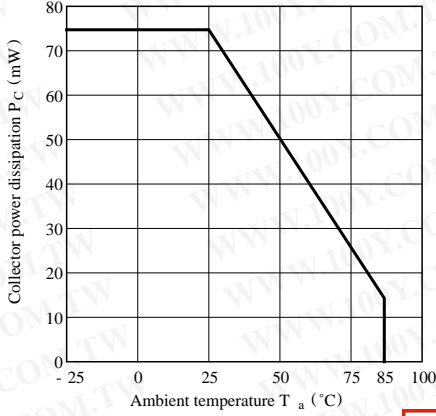


Fig. 2 Collector Dark Current vs. Ambient Temperature

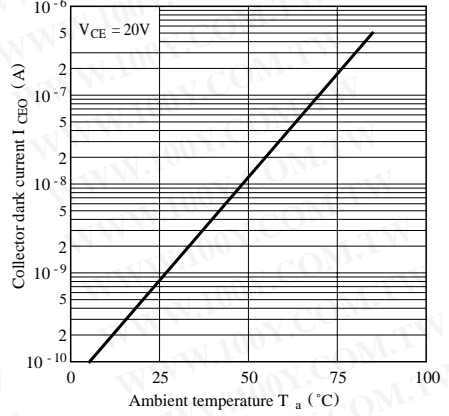
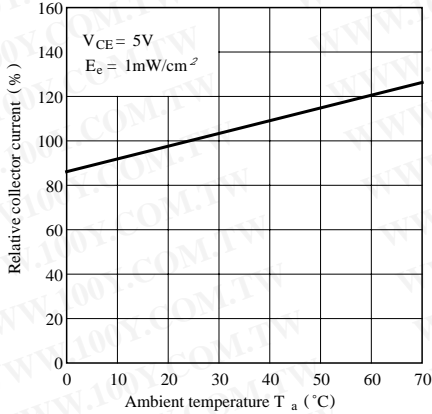


Fig. 3 Relative Collector Current vs. Ambient Temperature



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Fig.4-a Collector Current vs. Irradiance (PT480)

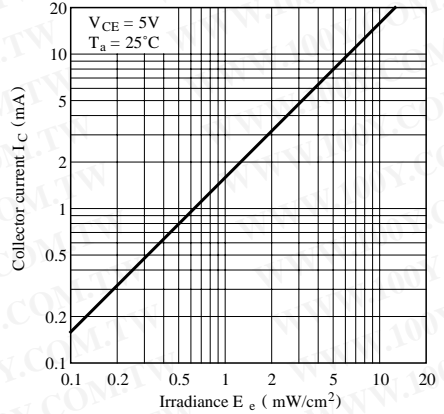


Fig.4-b Collector Current vs. Irradiance (PT480F)

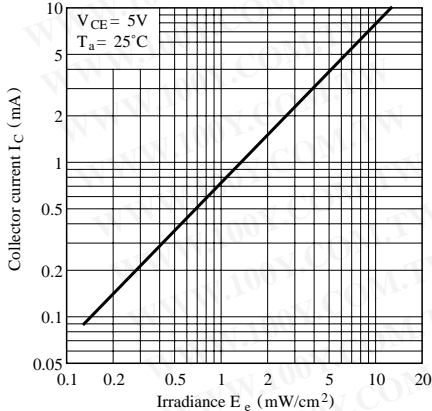


Fig.5-a Collector Current vs. Collector-emitter Voltage (PT480)

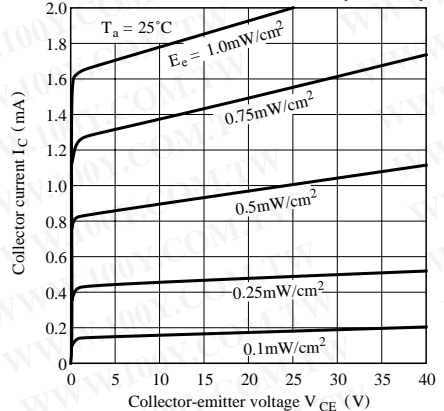


Fig.5-b Collector Current vs. Collector-emitter Voltage (PT480F)

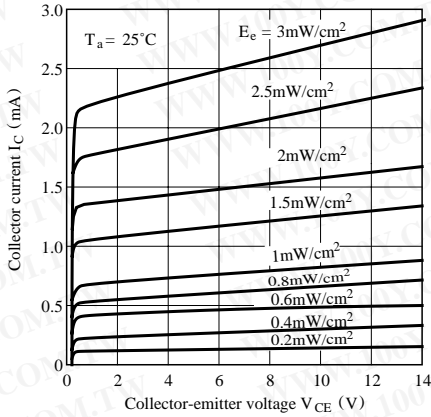


Fig. 6 Spectral Sensitivity

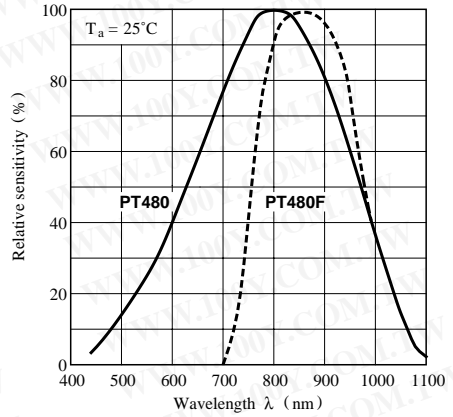
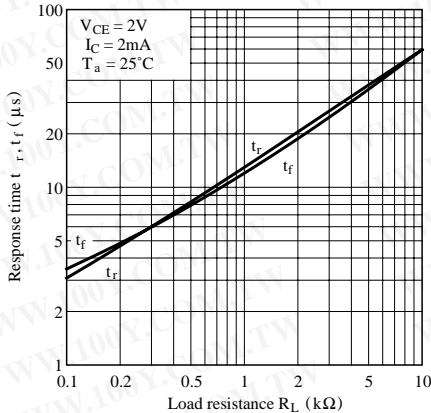
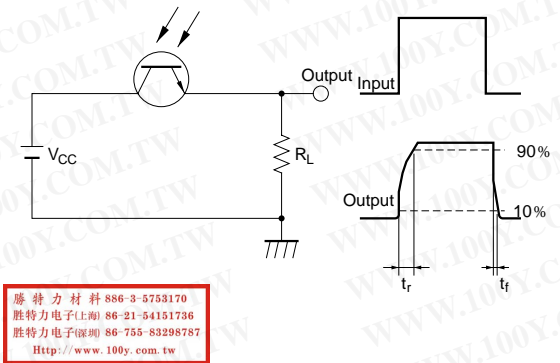


Fig. 7 Response Time vs. Load Resistance



Test Circuit for Response Time



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Fig. 8 Sensitivity Diagram (T_a = 25°C)

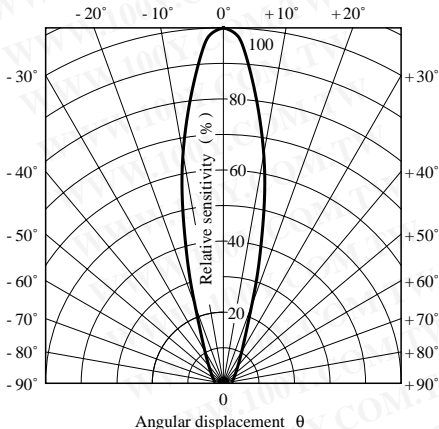


Fig.9-a Collector-emitter Saturation Voltage vs. Irradiance (PT480)

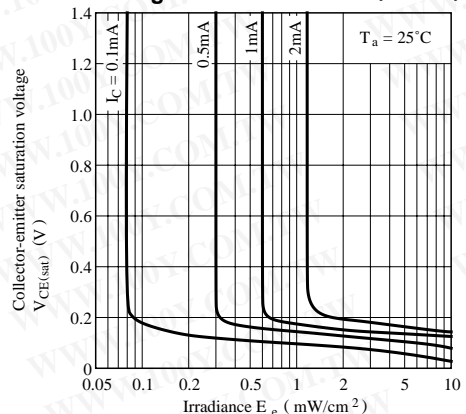


Fig.9-b Collector-emitter Saturation Voltage vs. Irradiance (PT480F)

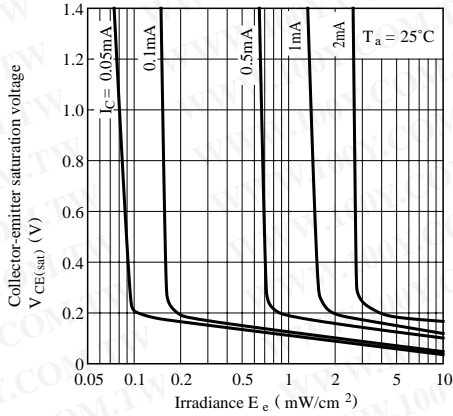
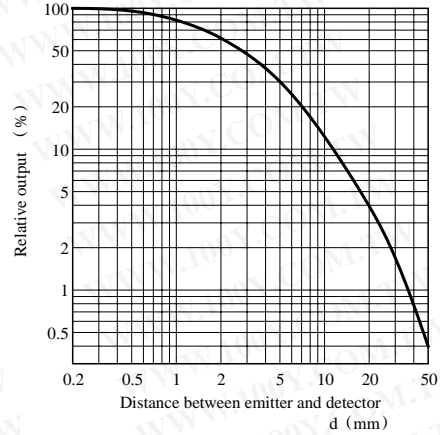


Fig.10 Relative Output vs. Distance (Emitter : GL480)



Please refer to the chapter "Precautions for Use."

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